

Dose Rate Monitoring System of BESIII

YE Mei

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YE Mei @ Cylindrical GEM mini-Workshop



Outline

- Short Introduction
 - Dose rate monitoring near IP based on PIN Diodes
 - Integrated Dose Monitoring for CsI Crystals based on RadFETs
- Brief status of the radiation Detectors
- Background



Background from

- Collision area near accelerator magnet synchrotron radiation photon
- Beam gas inelastic bremsstrahlung, Coulomb scattering, Touschek effect (the particles loss caused by the elastic scattering within the bunch between charged particles)
- Injection efficiency (Injection cause loss of particles less than 100%)
- Catastrophic loss: such as a vacuum leak, the magnetic field, power-down, the beam instability caused by the loss of particles



Framework of Pin Diode Dose Rate Monitoring System

- PIN Diodes
 - IP: 12
 - Endcap EMC: 4
- Cables
- Readout Electronics
- Read out PC
- Database





PIN Diodes installation at IP



- Size < 50(z)×24(x)×15(y) mm
- 30cm near colliding point
- sensors are distributed isometricly in circumferential direction
- 6 each for East/West





Readout Electronics



- 12 Detector input
- 1 Alarm out to Interlock
- ~220V power supply

2U Crate installed in 3rd floor of electronics hall Communication with Ethernet



Naming Convention of the Sensor



- Readings are processed by
 - temperature compensation
 - pedestal cut

Naming conventions

- DR#[1-12]
- S for second
- **M** for minute
- D for day



Snapshot from GUI





12 Pin Diodes Dose Rate per Day





Dark current DR#[1-12]





Integrated Dose Monitor - RadFETs



- Readout Electronics
 - 3U Crate
 - 8 boards,10
 channels each
 - ~220V Power Supply
- Communication with Ethernet



- 40 for barrel EMC
- 32 for Endcap EMC





Integrated Dose Rate from RedFET

Integral luminosity average vs Dose_max and Dose_mean





Integral RedFETs for each point (14 Apr. 2012 –14 Apr. 2013)





- The dose rate can be retrieved from the webpage of slow control
- Background → DoseRate → DRD, DRM, DRS
- Background → RedFET → Dose_max, Dose_mean
- DAQ RUN INFO → IntergralLumAvg
- Reference webpage
 - <u>http://bes3.ihep.ac.cn/</u> or Inner ip
 <u>http://192.168.43.211/cxh/SlowWeb/index.php</u>
 - Historical data backup before Oct. 2011 retrieved from inner ip:<u>http://192.168.37.164/SlowWeb/index.php</u>



Background Study

- The background affected by many factors
 - synchrotron radiation
 - beam-gas interactions
 - Touschek effect
 - injection loss
- A lot of work have been done
 - Simulated background study
 - Count rate from MDC chamber
 - Circulating beam experiment
 - Trg rate & DAQ event rate?
- Running background



Requirement issues

- Current status
 - Real time monitoring from the local software
 - There are no measurement for integral dose rate near IP till now
- There are many work to do for background study



Thank You!



PIN Diodes at Endcap EMC

